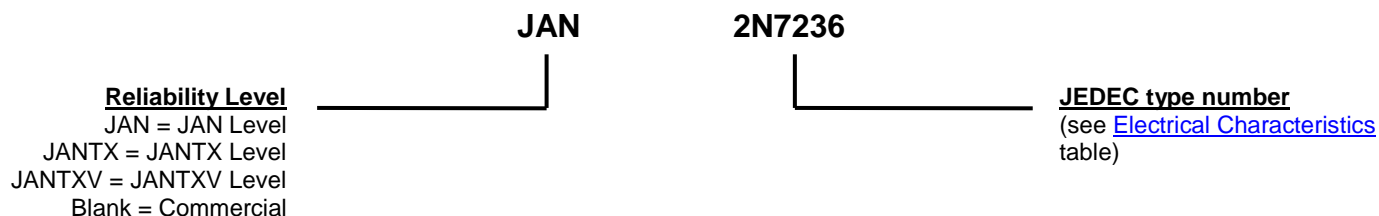


MECHANICAL and PACKAGING

- CASE: Ceramic and gold over nickel plated steel.
- TERMINALS: Gold over nickel plated tungsten/copper.
- MARKING: Manufacturer's ID, part number, date code, BeO.
- WEIGHT: 6.5 grams.
- See [Package Dimensions](#) on last page.

PART NOMENCLATURE**SYMBOLS & DEFINITIONS**

Symbol	Definition
di/dt	Rate of change of diode current while in reverse-recovery mode, recorded as maximum value.
I_F	Forward current
R_G	Gate drive impedance
V_{DD}	Drain supply voltage
V_{DS}	Drain source voltage, dc
V_{GS}	Gate source voltage, dc

ELECTRICAL CHARACTERISTICS @ $T_A = +25\text{ }^{\circ}\text{C}$, unless otherwise noted

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS				
Drain-Source Breakdown Voltage $V_{GS} = 0\text{ V}$, $I_D = 1.0\text{ mA}$	$V_{(BR)DSS}$	-100		V
Gate-Source Voltage (Threshold) $V_{DS} \geq V_{GS}$, $I_D = -0.25\text{ mA}$ $V_{DS} \geq V_{GS}$, $I_D = -0.25\text{ mA}$, $T_J = +125\text{ }^{\circ}\text{C}$ $V_{DS} \geq V_{GS}$, $I_D = -0.25\text{ mA}$, $T_J = -55\text{ }^{\circ}\text{C}$	$V_{GS(th)1}$ $V_{GS(th)2}$ $V_{GS(th)3}$	-2.0 -1.0	-4.0 -5.0	V
Gate Current $V_{GS} = \pm 20\text{ V}$, $V_{DS} = 0\text{ V}$ $V_{GS} = \pm 20\text{ V}$, $V_{DS} = 0\text{ V}$, $T_J = +125\text{ }^{\circ}\text{C}$	I_{GSS1} I_{GSS2}		± 100 ± 200	nA
Drain Current $V_{GS} = 0\text{ V}$, $V_{DS} = -80\text{ V}$	I_{DSS1}		-25	μA
Drain Current $V_{GS} = 0\text{ V}$, $V_{DS} = -100\text{ V}$, $T_J = +125\text{ }^{\circ}\text{C}$	I_{DSS2}		-1.0	mA
Drain Current $V_{GS} = 0\text{ V}$, $V_{DS} = -80\text{ V}$, $T_J = +125\text{ }^{\circ}\text{C}$	I_{DSS3}		-0.25	mA
Static Drain-Source On-State Resistance $V_{GS} = 10\text{ V}$, $I_D = -11.0\text{ A}$ pulsed	$r_{DS(on)1}$		0.20	Ω
Static Drain-Source On-State Resistance $V_{GS} = -10\text{ V}$, $I_D = -18.0\text{ A}$ pulsed	$r_{DS(on)2}$		0.22	Ω
Static Drain-Source On-State Resistance $T_J = +125\text{ }^{\circ}\text{C}$ $V_{GS} = -10\text{ V}$, $I_D = -11.0\text{ A}$ pulsed	$r_{DS(on)3}$		0.34	Ω
Diode Forward Voltage $V_{GS} = 0\text{ V}$, $I_D = -18.0\text{ A}$ pulsed	V_{SD}		-5.0	V

DYNAMIC CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Gate Charge:				
On-State Gate Charge $V_{GS} = -10\text{ V}$, $I_D = -18.0\text{ A}$, $V_{DS} = -50\text{ V}$	$Q_{g(on)}$		60	nC
Gate to Source Charge $V_{GS} = -10\text{ V}$, $I_D = -18.0\text{ A}$, $V_{DS} = -50\text{ V}$	Q_{gs}		13	nC
Gate to Drain Charge $V_{GS} = -10\text{ V}$, $I_D = -18.0\text{ A}$, $V_{DS} = -50\text{ V}$	Q_{gd}		35.2	nC

ELECTRICAL CHARACTERISTICS @ $T_A = +25\text{ }^{\circ}\text{C}$, unless otherwise noted (continued)**SWITCHING CHARACTERISTICS**

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Turn-on delay time $I_D = -11.0\text{ A}$, $V_{GS} = -10\text{ V}$, $R_G = 9.1\text{ }\Omega$, $V_{DD} = -50\text{ V}$	$t_{d(on)}$		35	ns
Rinse time $I_D = -11.0\text{ A}$, $V_{GS} = -10\text{ V}$, $R_G = 9.1\text{ }\Omega$, $V_{DD} = -50\text{ V}$	t_r		85	ns
Turn-off delay time $I_D = -11.0\text{ A}$, $V_{GS} = -10\text{ V}$, $R_G = 9.1\text{ }\Omega$, $V_{DD} = -50\text{ V}$	$t_{d(off)}$		85	ns
Fall time $I_D = -11.0\text{ A}$, $V_{GS} = -10\text{ V}$, $R_G = 9.1\text{ }\Omega$, $V_{DD} = -50\text{ V}$	t_f		65	ns
Diode Reverse Recovery Time $di/dt \leq 100\text{ A}/\mu\text{s}$, $V_{DD} \leq 30\text{ V}$, $I_F = -18.0\text{ A}$	t_{rr}		280	ns

GRAPHS

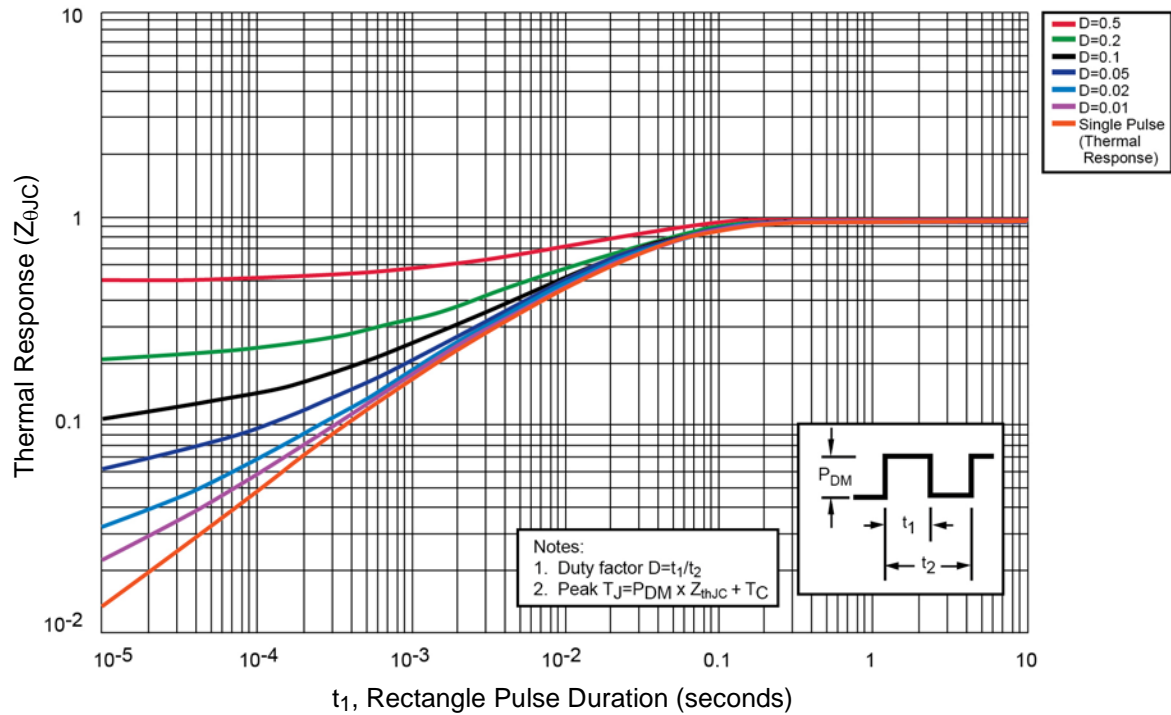


FIGURE 1
Thermal Impedance Curves

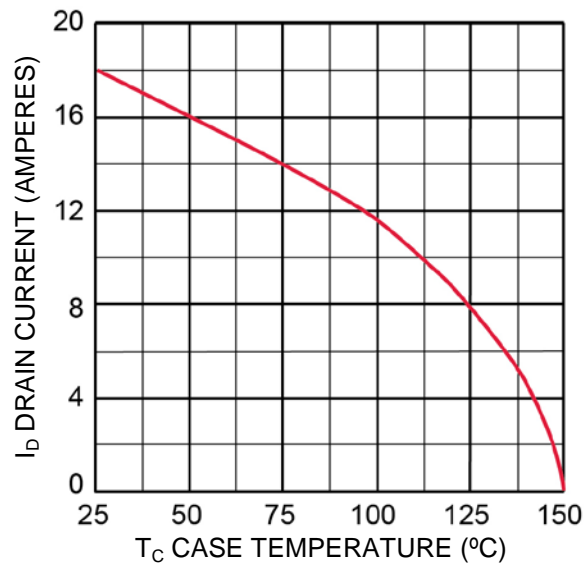


FIGURE 2
Maximum Drain Current vs Case Temperature Graphs

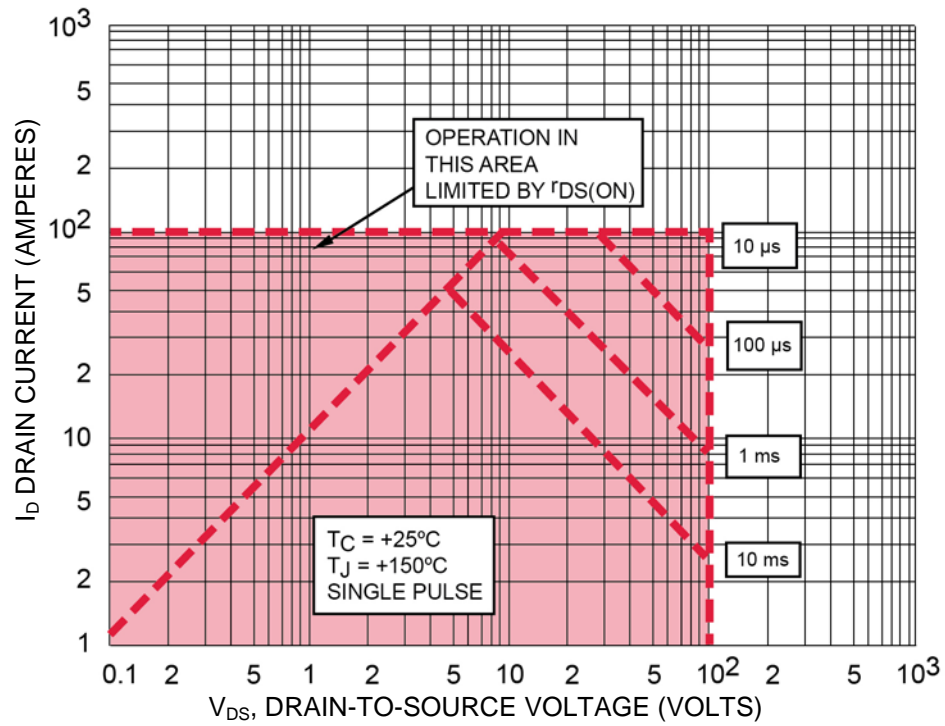
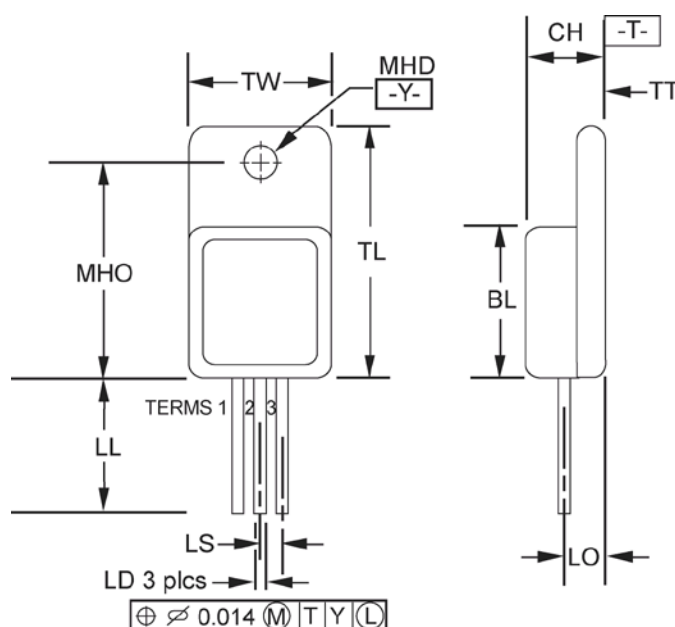
GRAPHS (continued)


FIGURE 3
Maximum Safe Operating Area

PACKAGE DIMENSIONS

NOTES:

1. Dimensions are in inches.
2. Millimeters are given for general information only.
3. Protrusion thickness of ceramic eyelets included in dimension LL.
4. All terminals are isolated from case.
5. In accordance with ASME Y14.5M, diameters are equivalent to Φ x symbology.

Ltr	Dimensions				Notes
	Inch		Millimeters		
	Min	Max	Min	Max	
BL	.535	.545	13.59	13.84	
CH	.249	.260	6.32	6.60	
LD	.035	.045	0.89	1.14	
LL	.510	.570	12.95	14.48	3
LO	.150 BSC		3.81 BSC		
LS	.150 BSC		3.81 BSC		
MHD	.139	.149	3.53	3.78	
MHO	.665	.685	16.89	17.40	
TL	.790	.800	20.07	20.32	4
TT	.040	.050	1.02	1.27	4
TW	.535	.545	13.59	13.84	
Term 1	Drain				
Term 2	Source				
Term 3	Gate				